

# HEF4017B

## 5-stage Johnson decade counter

Rev. 04 — 9 December 2008

Product data sheet

### 1. General description

The HEF4017B is a 5-stage Johnson decade counter with ten spike-free decoded active HIGH outputs (Q0 to Q9), an active LOW carry output from the most significant flip-flop ( $\overline{Q}5-9$ ), active HIGH and active LOW clock inputs (CP0,  $\overline{CP}1$ ) and an overriding asynchronous master reset input (MR).

The counter is advanced by either a LOW-to-HIGH transition at CP0 while  $\overline{CP}1$  is LOW or a HIGH-to-LOW transition at  $\overline{CP}1$  while CP0 is HIGH (see [Table 3](#)).

When cascading counters, the  $\overline{Q}5-9$  output, which is LOW while the counter is in states 5, 6, 7, 8, and 9, can be used to drive the CP0 input of the next counter. A HIGH on MR resets the counter to zero (Q0 =  $\overline{Q}5-9$  = HIGH; Q1 to Q9 = LOW) independent of the clock inputs (CP0,  $\overline{CP}1$ ).

Automatic counter code correction is provided by an internal circuit: following any illegal code the counter returns to a proper counting mode within 11 clock pulses.

Schmitt trigger action makes the clock inputs highly tolerant of slower rise and fall times.

It operates over a recommended  $V_{DD}$  power supply range of 3 V to 15 V referenced to  $V_{SS}$  (usually ground). Unused inputs must be connected to  $V_{DD}$ ,  $V_{SS}$ , or another input. It is also suitable for use over both the industrial ( $-40\text{ }^{\circ}\text{C}$  to  $+85\text{ }^{\circ}\text{C}$ ) and automotive ( $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$ ) temperature ranges.

### 2. Features

- Automatic counter correction
- Tolerant of slow clock rise and fall times
- Fully static operation
- 5 V, 10 V, and 15 V parametric ratings
- Standardized symmetrical output characteristics
- Operates across the automotive temperature range  $-40\text{ }^{\circ}\text{C}$  to  $+125\text{ }^{\circ}\text{C}$
- Complies with JEDEC standard JESD 13-B
- ESD protection:
  - ◆ HBM JESD22-A114E exceeds 2000 V
  - ◆ MM JESD22-A115-A exceeds 200 V

### 3. Applications

- Industrial and automotive

### 4. Ordering information

**Table 1. Ordering information**  
All types operate from -40 °C to +125 °C

Type number	Package		Version
	Name	Description	
HEF4017BP	DIP16	plastic dual in-line package; 16-leads (300 mil)	SOT38-4
HEF4017BT	SO16	plastic small outline package; 16 leads; body width 3.9 mm	SOT109-1

### 5. Functional diagram

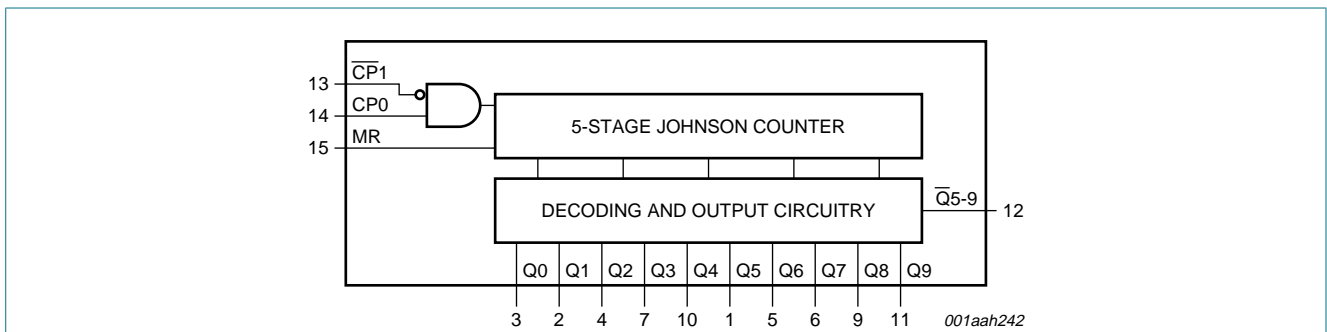


Fig 1. Functional diagram

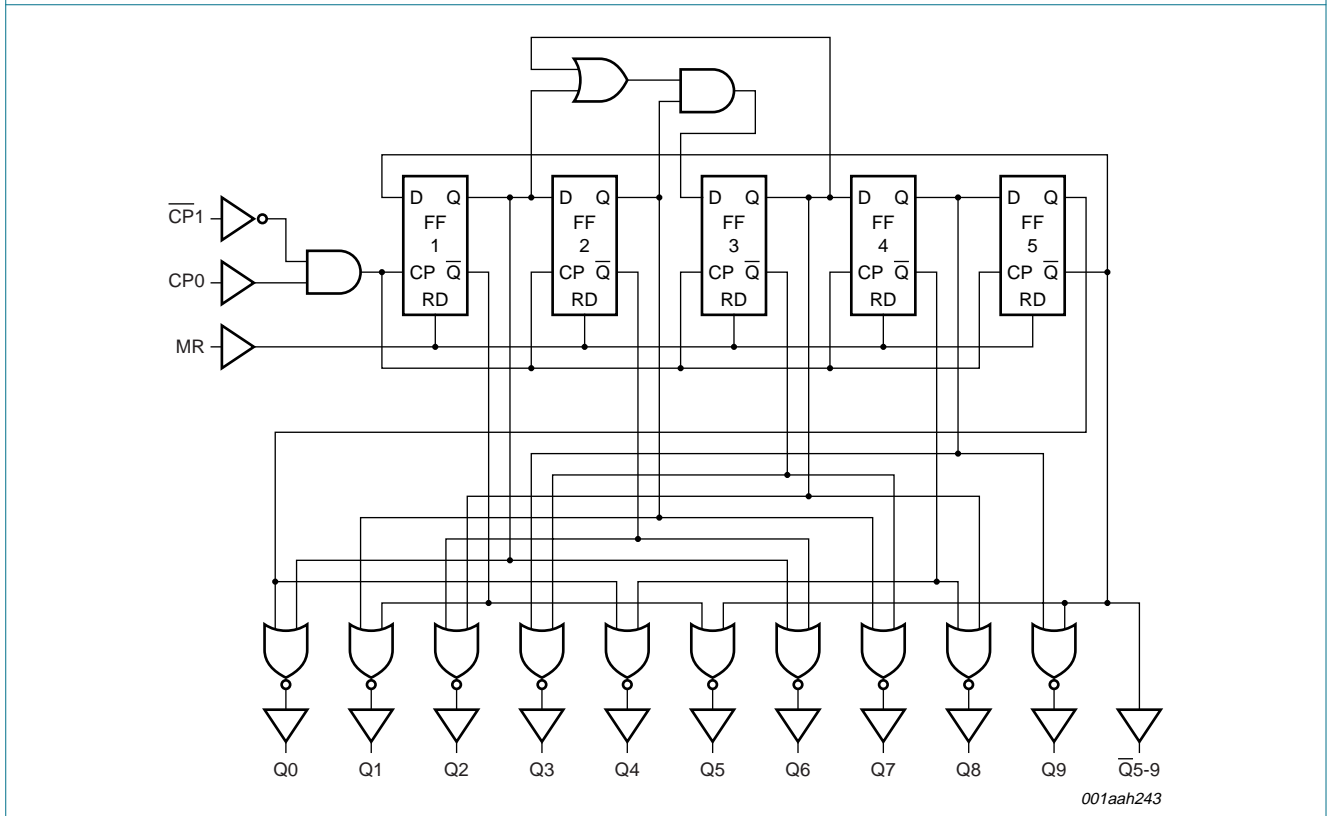


Fig 2. Logic diagram

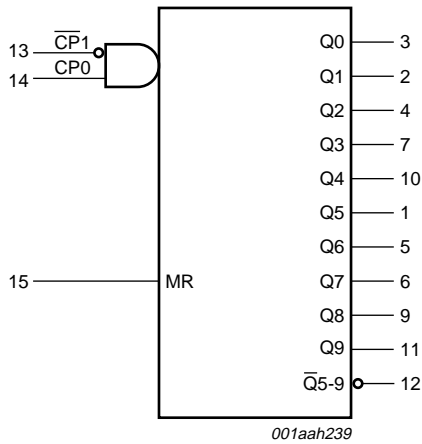


Fig 3. Logic symbol

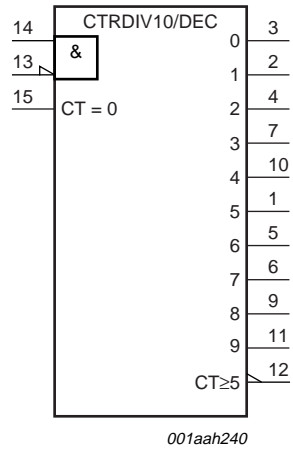


Fig 4. IEE logic symbol

## 6. Pinning information

### 6.1 Pinning

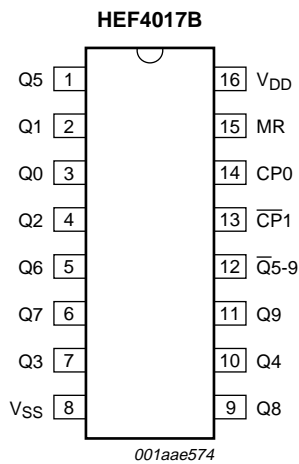


Fig 5. Pin configuration

### 6.2 Pin description

Table 2. Pin description

Symbol	Pin	Description
Q0 to Q9	3, 2, 4, 7, 10, 1, 5, 6, 9, 11	decoded output
V <sub>SS</sub>	8	ground supply voltage
Q <sub>5-9</sub>	12	carry output (active LOW)
CP1	13	clock input (HIGH-to-LOW edge-triggered)

Table 2. Pin description ...continued

Symbol	Pin	Description
CP0	14	clock input (LOW-to-HIGH edge-triggered)
MR	15	master reset input
V <sub>DD</sub>	16	supply voltage

## 7. Functional description

Table 3. Function table [1]

MR	CP0	CP1	Operation
H	X	X	Q0 = $\overline{Q}5-9 = H$ ; Q1 to Q9 = L
L	H	↓	counter advances
L	↑	L	counter advances
L	L	X	no change
L	X	H	no change
L	H	↑	no change
L	↓	L	no change

[1] H = HIGH voltage level; L = LOW voltage level; X = don't care;  
 ↑ = positive-going transition; ↓ = negative-going transition.

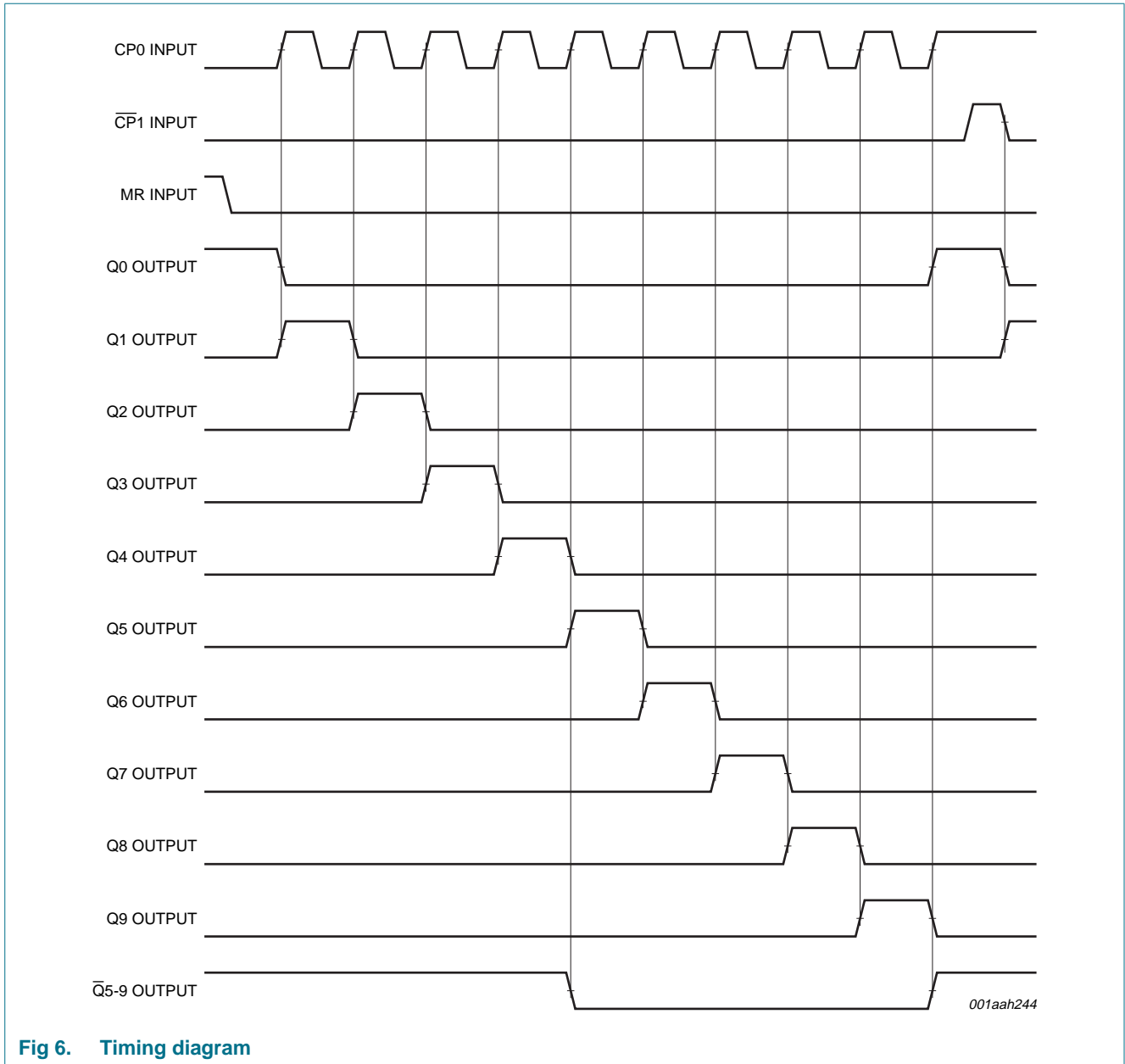


Fig 6. Timing diagram

## 8. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{DD}$	supply voltage		-0.5	+18	V
$I_{IK}$	input clamping current	$V_I < 0.5\text{ V}$ or $V_I > V_{DD} + 0.5\text{ V}$	-	$\pm 10$	mA
$V_I$	input voltage		-0.5	$V_{DD} + 0.5$	V
$I_{OK}$	output clamping current	$V_O < 0.5\text{ V}$ or $V_O > V_{DD} + 0.5\text{ V}$	-	$\pm 10$	mA
$I_{I/O}$	input/output current		-	$\pm 10$	mA

**Table 4. Limiting values ...continued**  
In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Max	Unit
$I_{DD}$	supply current		-	50	mA
$T_{stg}$	storage temperature		-65	+150	°C
$T_{amb}$	ambient temperature		-40	+125	°C
$P_{tot}$	total power dissipation	$T_{amb} = -40\text{ °C to }+125\text{ °C}$			
		DIP16 package	[1] -	750	mW
		SO16 package	[2] -	500	mW
$P$	power dissipation	per output	-	100	mW

[1] For DIP16 package:  $P_{tot}$  derates linearly with 12 mW/K above 70 °C.

[2] For SO16 package:  $P_{tot}$  derates linearly with 8 mW/K above 70 °C.

## 9. Recommended operating conditions

**Table 5. Recommended operating conditions**

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
$V_{DD}$	supply voltage		3	-	15	V
$V_I$	input voltage		0	-	$V_{DD}$	V
$T_{amb}$	ambient temperature	in free air	-40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{DD} = 5\text{ V}$	-	-	3.75	ns/V
		$V_{DD} = 10\text{ V}$	-	-	0.5	ns/V
		$V_{DD} = 15\text{ V}$	-	-	0.08	ns/V

## 10. Static characteristics

**Table 6. Static characteristics**  
 $V_{SS} = 0\text{ V}$ ;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

Symbol	Parameter	Conditions	$V_{DD}$	$T_{amb} = -40\text{ °C}$		$T_{amb} = 25\text{ °C}$		$T_{amb} = 85\text{ °C}$		$T_{amb} = 125\text{ °C}$		Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
$V_{IH}$	HIGH-level input voltage	$ I_O  < 1\ \mu\text{A}$	5 V	3.5	-	3.5	-	3.5	-	3.5	-	V
			10 V	7.0	-	7.0	-	7.0	-	7.0	-	V
			15 V	11.0	-	11.0	-	11.0	-	11.0	-	V
$V_{IL}$	LOW-level input voltage	$ I_O  < 1\ \mu\text{A}$	5 V	-	1.5	-	1.5	-	1.5	-	1.5	V
			10 V	-	3.0	-	3.0	-	3.0	-	3.0	V
			15 V	-	4.0	-	4.0	-	4.0	-	4.0	V
$V_{OH}$	HIGH-level output voltage	$ I_O  < 1\ \mu\text{A}$ ; $V_I = V_{SS}$ or $V_{DD}$	5 V	4.95	-	4.95	-	4.95	-	4.95	-	V
			10 V	9.95	-	9.95	-	9.95	-	9.95	-	V
			15 V	14.95	-	14.95	-	14.95	-	14.95	-	V
$V_{OL}$	LOW-level output voltage	$ I_O  < 1\ \mu\text{A}$ ; $V_I = V_{SS}$ or $V_{DD}$	5 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			10 V	-	0.05	-	0.05	-	0.05	-	0.05	V
			15 V	-	0.05	-	0.05	-	0.05	-	0.05	V

**Table 6. Static characteristics ...continued**  
 $V_{SS} = 0\text{ V}$ ;  $V_I = V_{SS}$  or  $V_{DD}$  unless otherwise specified.

Symbol	Parameter	Conditions	V <sub>DD</sub>	T <sub>amb</sub> = -40 °C		T <sub>amb</sub> = 25 °C		T <sub>amb</sub> = 85 °C		T <sub>amb</sub> = 125 °C		Unit
				Min	Max	Min	Max	Min	Max	Min	Max	
I <sub>OH</sub>	HIGH-level output current	V <sub>O</sub> = 2.5 V	5 V	-1.7	-	-1.4	-	-1.1	-	-1.1	-	mA
		V <sub>O</sub> = 4.6 V	5 V	-0.64	-	-0.5	-	-0.36	-	-0.36	-	mA
		V <sub>O</sub> = 9.5 V	10 V	-1.6	-	-1.3	-	-0.9	-	-0.9	-	mA
		V <sub>O</sub> = 13.5 V	15 V	-4.2	-	-3.4	-	-2.4	-	-2.4	-	mA
I <sub>OL</sub>	LOW-level output current	V <sub>O</sub> = 0.4 V	5 V	0.64	-	0.5	-	0.36	-	0.36	-	mA
		V <sub>O</sub> = 0.5 V	10 V	1.6	-	1.3	-	0.9	-	0.9	-	mA
		V <sub>O</sub> = 1.5 V	15 V	4.2	-	3.2	-	2.4	-	2.4	-	mA
I <sub>I</sub>	input leakage current		15 V	-	±0.1	-	±0.1	-	±1.0	-	±1.0	µA
I <sub>DD</sub>	supply current	I <sub>O</sub> = 0 A;	5 V	-	5	-	5	-	150	-	150	µA
		V <sub>I</sub> = V <sub>SS</sub> or V <sub>DD</sub>	10 V	-	10	-	10	-	300	-	300	µA
			15 V	-	20	-	20	-	600	-	600	µA
C <sub>I</sub>	input capacitance		-	-	-	7.5	-	-	-	-	pF	

## 11. Dynamic characteristics

**Table 7. Dynamic characteristics**  
 $T_{amb} = 25\text{ °C}$ ;  $V_{SS} = 0\text{ V}$ ; for test circuit see [Figure 10](#)

Symbol	Parameter	Conditions	V <sub>DD</sub>	Extrapolation formula <sup>[1]</sup>	Min	Typ	Max	Unit
t <sub>PHL</sub>	HIGH to LOW propagation delay	CP0, $\overline{CP1} \rightarrow Q0$ to Q9; see <a href="#">Figure 7</a>	5 V	113 ns + (0.55 ns/pF) C <sub>L</sub>	-	140	280	ns
			10 V	44 ns + (0.23 ns/pF) C <sub>L</sub>	-	55	110	ns
			15 V	32 ns + (0.16 ns/pF) C <sub>L</sub>	-	40	80	ns
		CP0, $\overline{CP1} \rightarrow \overline{Q5-9}$ ; see <a href="#">Figure 7</a>	5 V	118 ns + (0.55 ns/pF) C <sub>L</sub>	-	145	290	ns
			10 V	44 ns + (0.23 ns/pF) C <sub>L</sub>	-	55	110	ns
			15 V	32 ns + (0.16 ns/pF) C <sub>L</sub>	-	40	80	ns
		MR $\rightarrow Q1$ to Q9; see <a href="#">Figure 8</a>	5 V	88 ns + (0.55 ns/pF) C <sub>L</sub>	-	115	230	ns
			10 V	39 ns + (0.23 ns/pF) C <sub>L</sub>	-	50	100	ns
			15 V	27 ns + (0.16 ns/pF) C <sub>L</sub>	-	35	70	ns

**Table 7. Dynamic characteristics ...continued**  
 $T_{amb} = 25\text{ }^{\circ}\text{C}$ ;  $V_{SS} = 0\text{ V}$ ; for test circuit see [Figure 10](#)

Symbol	Parameter	Conditions	V <sub>DD</sub>	Extrapolation formula <sup>[1]</sup>	Min	Typ	Max	Unit
t <sub>PLH</sub>	LOW to HIGH propagation delay	CP0, $\overline{\text{CP}}1 \rightarrow \text{Q0 to Q9}$ ; see <a href="#">Figure 7</a>	5 V	98 ns + (0.55 ns/pF) C <sub>L</sub>	-	125	250	ns
			10 V	39 ns + (0.23 ns/pF) C <sub>L</sub>	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF) C <sub>L</sub>	-	40	80	ns
		CP0, $\overline{\text{CP}}1 \rightarrow \overline{\text{Q}}5-9$ ; see <a href="#">Figure 7</a>	5 V	98 ns + (0.55 ns/pF) C <sub>L</sub>	-	125	250	ns
			10 V	39 ns + (0.23 ns/pF) C <sub>L</sub>	-	50	100	ns
			15 V	32 ns + (0.16 ns/pF) C <sub>L</sub>	-	40	80	ns
		MR $\rightarrow \overline{\text{Q}}5-9$ ; see <a href="#">Figure 8</a>	5 V	83 ns + (0.55 ns/pF) C <sub>L</sub>	-	110	220	ns
			10 V	34 ns + (0.23 ns/pF) C <sub>L</sub>	-	45	90	ns
			15 V	27 ns + (0.16 ns/pF) C <sub>L</sub>	-	35	70	ns
		MR $\rightarrow \text{Q0}$ ; see <a href="#">Figure 8</a>	5 V	103 ns + (0.55 ns/pF) C <sub>L</sub>	-	130	260	ns
			10 V	44 ns + (0.23 ns/pF) C <sub>L</sub>	-	55	105	ns
			15 V	32 ns + (0.16 ns/pF) C <sub>L</sub>	-	40	75	ns
t <sub>t</sub>	transition time	see <a href="#">Figure 7</a>	5 V	<sup>[2]</sup> 10 ns + (1.00 ns/pF) C <sub>L</sub>	-	60	120	ns
			10 V	9 ns + (0.42 ns/pF) C <sub>L</sub>	-	30	60	ns
			15 V	6 ns + (0.28 ns/pF) C <sub>L</sub>	-	20	40	ns
t <sub>h</sub>	hold time	CP0 $\rightarrow \overline{\text{CP}}1$ ; see <a href="#">Figure 9</a>	5 V		90	45	-	ns
			10 V		40	20	-	ns
			15 V		20	10	-	ns
		$\overline{\text{CP}}1 \rightarrow \text{CP0}$ ; see <a href="#">Figure 9</a>	5 V		80	40	-	ns
			10 V		40	20	-	ns
			15 V		30	10	-	ns
t <sub>w</sub>	pulse width	CP0 input LOW; minimum width; see <a href="#">Figure 8</a>	5 V		80	40	-	ns
			10 V		40	20	-	ns
			15 V		30	15	-	ns
		$\overline{\text{CP}}1$ input HIGH; minimum width; see <a href="#">Figure 8</a>	5 V		80	40	-	ns
			10 V		40	20	-	ns
			15 V		30	15	-	ns
		MR input HIGH; minimum width; see <a href="#">Figure 8</a>	5 V		50	25	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
t <sub>rec</sub>	recovery time	MR input; see <a href="#">Figure 8</a>	5 V		60	30	-	ns
			10 V		30	15	-	ns
			15 V		20	10	-	ns
f <sub>max</sub>	maximum frequency	see <a href="#">Figure 8</a>	5 V		6	12	-	MHz
			10 V		12	30	-	MHz
			15 V		15	30	-	MHz

[1] The typical values of the propagation delay and transition times are calculated from the extrapolation formulas shown (C<sub>L</sub> in pF).

[2] t<sub>t</sub> is the same as t<sub>THL</sub> and t<sub>TLH</sub>.

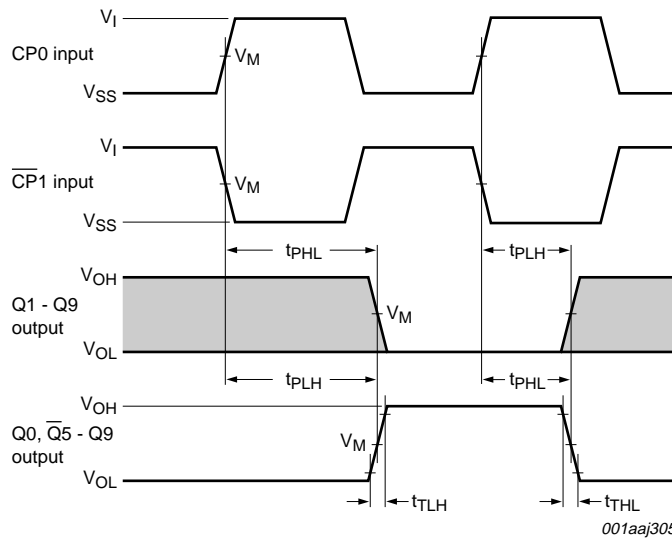


**Table 8. Dynamic power dissipation  $P_D$**

$P_D$  can be calculated from the formulas shown.  $V_{SS} = 0\text{ V}$ ;  $t_r = t_f \leq 20\text{ ns}$ ;  $T_{amb} = 25\text{ }^\circ\text{C}$ .

Symbol	Parameter	$V_{DD}$	Typical formula for $P_D$ ( $\mu\text{W}$ )	where:
$P_D$	dynamic power dissipation	5 V	$P_D = 500 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	$f_i$ = input frequency in MHz;
		10 V	$P_D = 2200 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	$f_o$ = output frequency in MHz;
		15 V	$P_D = 6000 \times f_i + \Sigma(f_o \times C_L) \times V_{DD}^2$	$C_L$ = output load capacitance in pF;
				$V_{DD}$ = supply voltage in V;
				$\Sigma(C_L \times f_o)$ = sum of the outputs.

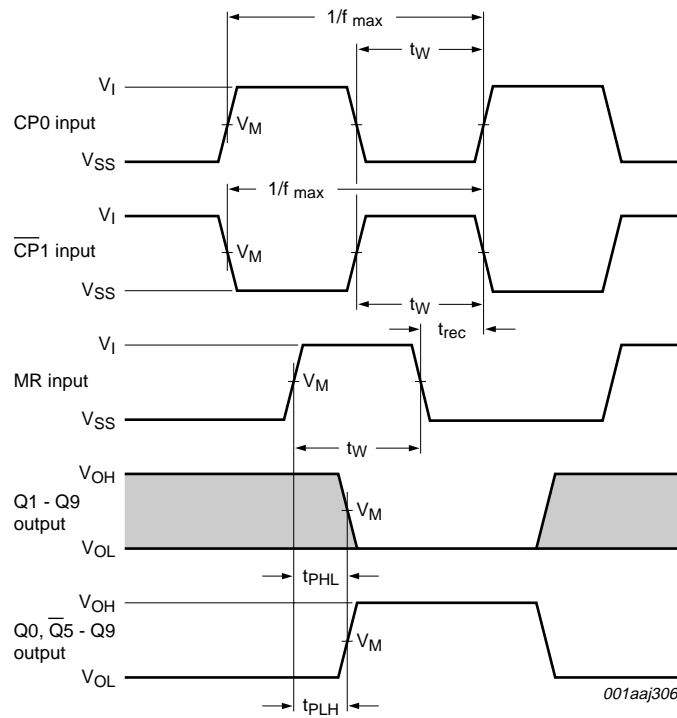
## 12. Waveforms



Conditions:  $\overline{CP1} = \text{LOW}$ , while CP0 triggers on a LOW-to-HIGH transition.  $\overline{CP1}$  triggers on a HIGH-to-LOW transition; The shaded areas indicate where the output state is set by the input count.

Measurement points given in [Table 9](#).

**Fig 7. Waveforms showing the propagation delays for CP0,  $\overline{CP1}$  to Qn,  $\overline{Q5-9}$  outputs and the output transition times**

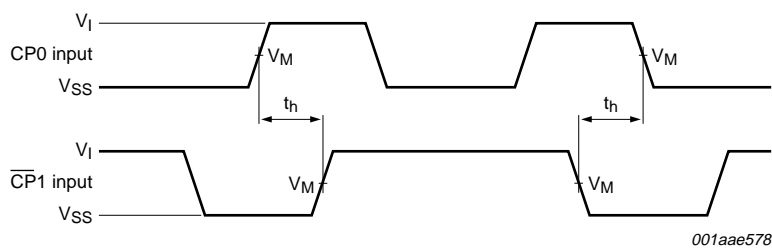


Conditions:  $\overline{CP1} = \text{LOW}$ , while CP0 triggers on a LOW-to-HIGH transition.  $t_W$  and  $t_{rec}$  are measured when CP0 = HIGH and  $\overline{CP1}$  triggers on a HIGH-to-LOW transition;

The shaded areas indicate where the output state is set by the input count.

Measurement points given in [Table 9](#).

**Fig 8. Waveforms showing the minimum pulse width for CP0,  $\overline{CP1}$  and MR input; the maximum frequency for CP0 and CP1 input; the recovery time for MR and the MR input to Qn and Q5-9 output propagation delays**



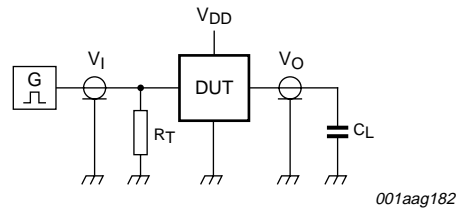
Hold times are shown as positive values, but may be specified as negative values;

Measurement points given in [Table 9](#).

**Fig 9. Waveforms showing hold times for CP0 to  $\overline{CP1}$  and  $\overline{CP1}$  to CP0**

**Table 9. Measurement points**

Supply voltage	Input	Output
$V_{DD}$	$V_M$	$V_M$
5 V to 15 V	$0.5V_{DD}$	$0.5V_{DD}$



Test data is given in [Table 10](#).

Definitions for test circuit:

DUT = Device Under Test;

$C_L$  = load capacitance including jig and probe capacitance;

$R_T$  = termination resistance should be equal to the output impedance  $Z_o$  of the pulse generator.

**Fig 10. Test circuit**

**Table 10. Test data**

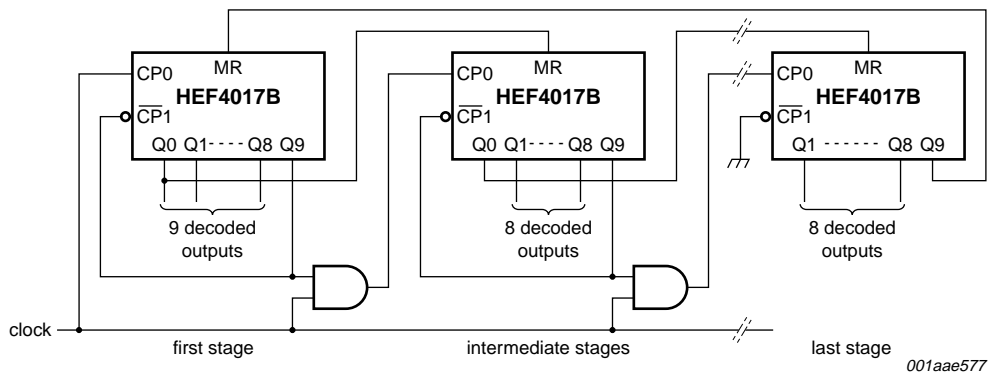
Supply voltage	Input	Load
$V_{DD}$	$V_I$	$C_L$
5 V to 15 V	$V_{SS}$ or $V_{DD}$	50 pF
	$t_r, t_f$	$\leq 20$ ns

### 13. Application information

Some examples of applications for the HEF4017B are:

- Decade counter with decimal decoding
- 1 out of n decoding counter (when cascaded)
- Sequential controller
- Timer

[Figure 11](#) shows a technique for extending the number of decoded output states for the HEF4017B. Decoded outputs are sequential within each stage and from stage to stage, with no dead time (except propagation delay).



Enabling the counter on  $\overline{CP1}$  when  $CP0$  is HIGH, or on  $CP0$  when  $\overline{CP1}$  is LOW, causes an extra count.

**Fig 11. Counter expansion**

14. Package outline

DIP16: plastic dual in-line package; 16 leads (300 mil)

SOT38-4

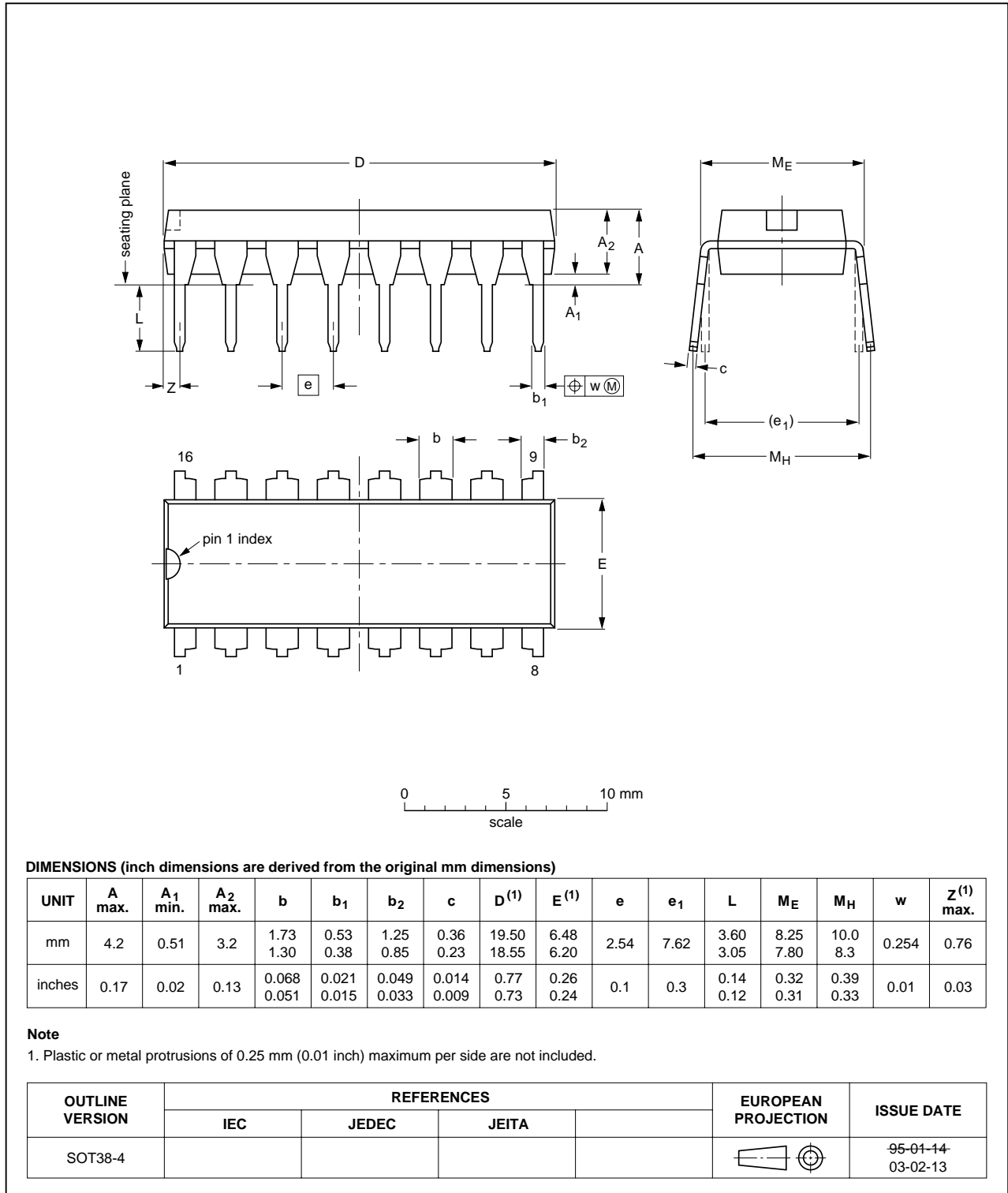


Fig 12. Package outline SOT38-4 (DIP16)

SO16: plastic small outline package; 16 leads; body width 3.9 mm

SOT109-1

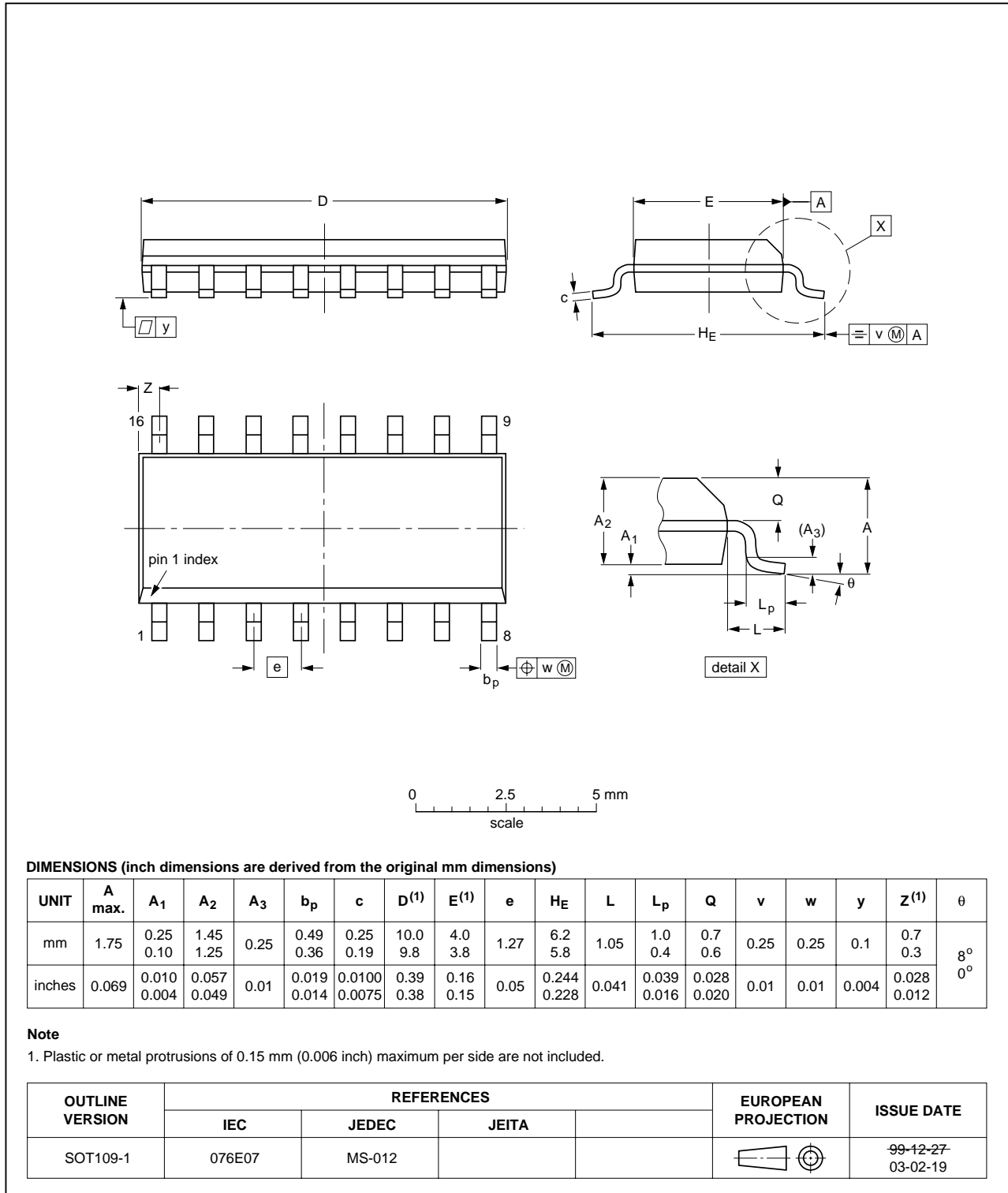


Fig 13. Package outline SOT109-1 (SO16)

## 15. Abbreviations

Table 11. Abbreviations

Acronym	Description
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model

## 16. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
HEF4017B_4	20081209	Product data sheet	-	HEF4017B_CNV_3
Modifications:	<ul style="list-style-type: none"> <li>• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors.</li> <li>• Legal texts have been adapted to the new company name where appropriate.</li> <li>• Rename the pins throughout to be consistent with rest of HEF family.</li> <li>• Increased the maximum ambient temperature to 125 °C throughout.</li> <li>• <a href="#">Section 2 “Features”</a> added.</li> <li>• Package version SOT38-1 changed to SOT38-4 in <a href="#">Section 4</a>, and <a href="#">Figure 12</a>. Package SOT74 removed from <a href="#">Section 4</a>.</li> <li>• <a href="#">Table 1 “Ordering information”</a> and <a href="#">Table 2 “Pin description”</a> restructured.</li> <li>• <a href="#">Figure 3 “Logic symbol”</a> and <a href="#">Figure 4 “IEE logic symbol”</a> added.</li> <li>• <a href="#">Section 8 “Limiting values”</a> and <a href="#">Section 10 “Static characteristics”</a> added, taken from the HE4000B Family Specifications data sheet.</li> <li>• <a href="#">Section 9 “Recommended operating conditions”</a> added.</li> <li>• <a href="#">Table 6 “Static characteristics”</a> restructured.</li> <li>• Values for <math>I_{DD}</math>, <math>I_{OL}</math> and <math>I_{OH}</math> updated in <a href="#">Table 6 “Static characteristics”</a>.</li> <li>• <math>t_{hold}</math> and <math>t_{RMR}</math> renamed to <math>t_h</math> hold time and <math>t_{rec}</math> recovery time in <a href="#">Table 7 “Dynamic characteristics”</a>. and <a href="#">Section 12 “Waveforms”</a>.</li> <li>• <math>t_{WCPL}</math>, <math>t_{WCPH}</math> and <math>t_{WMRH}</math> renamed to <math>t_W</math> minimum pulse width in <a href="#">Table 7 “Dynamic characteristics”</a>. and <a href="#">Section 12 “Waveforms”</a>.</li> <li>• <a href="#">Figure 7 “Waveforms showing the propagation delays for CP0, CP1 to Qn, Q5-9 outputs and the output transition times”</a> and <a href="#">Figure 10 “Test circuit”</a> added.</li> <li>• Maximum frequency and propagation added to <a href="#">Figure 8 “Waveforms showing the minimum pulse width for CP0, CP1 and MR input; the maximum frequency for CP0 and CP1 input; the recovery time for MR and the MR input to Qn and Q5-9 output propagation delays”</a>.</li> <li>• <a href="#">Section 14 “Package outline”</a> added.</li> </ul>			
HEF4017B_CNV_3	19950101	Product specification	-	HEF4017B_CNV_2
HEF4017B_CNV_2	19950101	Product specification	-	-

## 17. Legal information

### 17.1 Data sheet status

Document status <sup>[1][2]</sup>	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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